74LVC1G58

Low-power configurable multiple function gate

Rev. 12 — 18 August 2023

Product data sheet

1. General description

The 74LVC1G58 is a configurable multiple function gate with Schmitt-trigger inputs. The device can be configured as any of the following logic functions AND, OR, NAND, NOR, XOR, inverter and buffer; using the 3-bit input. All inputs can be connected diectly to $V_{\rm CC}$ or GND. Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of these devices as translators in mixed 3.3 V and 5 V environments.

This device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 1.65 V to 5.5 V
- High noise immunity
- ±24 mA output drive (V_{CC} = 3.0 V)
- CMOS low power dissipation
- I_{OFF} circuitry provides partial Power-down mode operation
- · Latch-up performance exceeds 250 mA
- · Direct interface with TTL levels
- Overvoltage tolerant inputs to 5.5 V
- Complies with JEDEC standard:
 - JESD8-7 (1.65 V to 1.95 V)
 - JESD8-5 (2.3 V to 2.7 V)
 - JESD8C (2.7 V to 3.6 V)
 - JESD36 (4.5 V to 5.5 V)
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- · Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C.



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3. Ordering information

Table 1. Ordering information

Type number	Package	Package						
	Temperature range	Name	Description	Version				
74LVC1G58GW	-40 °C to +125 °C	TSSOP6	plastic thin shrink small outline package; 6 leads; body width 1.25 mm	SOT363-2				
74LVC1G58GV	-40 °C to +125 °C	SC-74; TSOP6	plastic surface-mounted package; 6 leads	<u>SOT457</u>				
74LVC1G58GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	<u>SOT886</u>				
74LVC1G58GN	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	SOT1115				
74LVC1G58GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202				

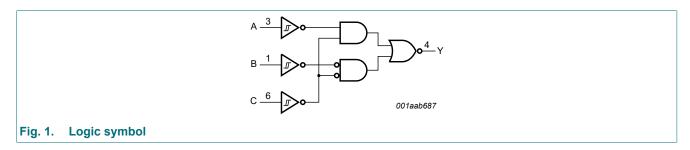
4. Marking

Table 2. Marking

Type number	Marking code [1]
74LVC1G58GW	YK
74LVC1G58GV	V58
74LVC1G58GM	YK
74LVC1G58GN	YK
74LVC1G58GS	YK

^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

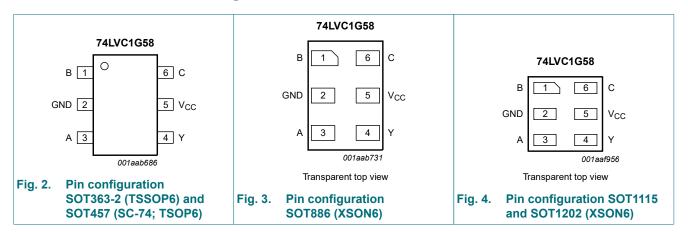
5. Functional diagram



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6. Pinning information

6.1. Pinning



6.2. Pin description

Table 3. Pin description

Symbol	Pin	Description		
В	1	data input		
GND	2	ground (0 V)		
A	3	data input		
Υ	4	data output		
V _{CC}	5	supply voltage		
С	6	data input		

7. Functional description

Table 4. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$

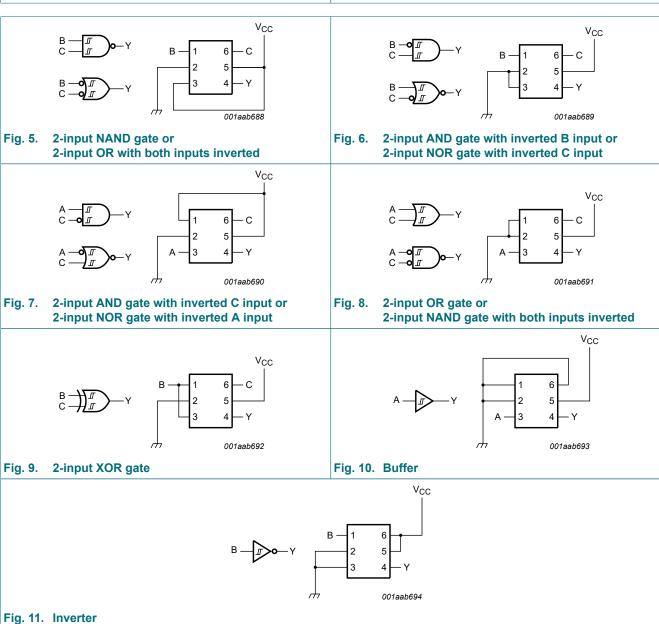
Inputs	Output		
С	В	A	Υ
L	L	L	L
L	L	Н	Н
L	Н	L	L
L	Н	Н	Н
Н	L	L	Н
Н	L	Н	Н
Н	Н	L	L
Н	Н	Н	L

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7.1. Logic configurations

Table 5. Function selection table

Logic function	Figure
2-input NAND	see Fig. 5
2-input NAND with both inputs inverted	see Fig. 8
2-input AND with inverted input	see Fig. 6 and Fig. 7
2-input NOR with inverted input	see Fig. 6 and Fig. 7
2-input OR	see Fig. 8
2-input OR with both inputs inverted	see Fig. 5
2-input XOR	see Fig. 9
Buffer	see Fig. 10
Inverter	see Fig. 11



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8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+6.5	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+6.5	V
I _{OK}	output clamping current	V _O > V _{CC} or V _O < 0 V	-	±50	mA
Vo	output voltage	Active mode [1]	-0.5	+6.5	V
		Power-down mode; V _{CC} = 0 V [1]	-0.5	+6.5	V
I _O	output current	V _O = 0 V to V _{CC}	-	±50	mA
I _{CC}	supply current		-	100	mA
I _{GND}	ground current		-100	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	T_{amb} = -40 °C to +125 °C [2]	-	250	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

For SOT457 (SC-74; TSOP6) package: Ptot derates linearly with 4.1 mW/K above 89 °C.

For SOT886 (XSON6) package: Ptot derates linearly with 3.3 mW/K above 74 °C.

For SOT1115 (XSON6) package: Ptot derates linearly with 3.2 mW/K above 71 °C.

For SOT1202 (XSON6) package: Ptot derates linearly with 3.3 mW/K above 74 °C.

9. Recommended operating conditions

Table 7. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CC}	supply voltage		1.65	-	5.5	V
VI	input voltage		0	-	5.5	V
Vo	output voltage	Active mode	0	-	V _{CC}	V
		Power-down mode; V _{CC} = 0 V	0	-	5.5	V
T _{amb}	ambient temperature		-40	-	+125	°C

^[2] For SOT363-2 (TSSOP6) package: Ptot derates linearly with 3.7 mW/K above 83 °C.

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10. Static characteristics

Table 8. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ [1]	Max	Unit
T _{amb} = -	40 °C to +85 °C		•			
V _{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = 100 μA; V _{CC} = 1.65 V to 5.5 V	-	-	0.1	V
		I _O = 4 mA; V _{CC} = 1.65 V	-	-	0.45	V
		I_{O} = 8 mA; V_{CC} = 2.3 V	-	-	0.3	V
		I _O = 12 mA; V _{CC} = 2.7 V	-	-	0.4	V
		I_{O} = 24 mA; V_{CC} = 3.0 V	-	-	0.55	V
		I_{O} = 32 mA; V_{CC} = 4.5 V	-	-	0.55	V
V _{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = -100 μA; V _{CC} = 1.65 V to 5.5 V	V _{CC} - 0.1	-	-	V
		I _O = -4 mA; V _{CC} = 1.65 V	1.2	-	-	V
		I _O = -8 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -12 mA; V _{CC} = 2.7 V	2.2	-	-	V
		I_{O} = -24 mA; V_{CC} = 3.0 V	2.3	-	-	V
		I_{O} = -32 mA; V_{CC} = 4.5 V	3.8	-	-	V
l _l	input leakage current	V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V	-	±0.1	±1	μA
I _{OFF}	power-off leakage current	V _I or V _O = 5.5 V; V _{CC} = 0 V	-	±0.1	±2	μΑ
I _{CC}	supply current	$V_I = 5.5 \text{ V or GND}; V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}; I_O = 0 \text{ A}$	-	0.1	4	μA
ΔI _{CC}	additional supply current	V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 2.3 V to 5.5 V	-	5	500	μΑ
Cı	input capacitance		-	2.5	-	pF

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Symbol	Parameter	Conditions	Min	Typ [1]	Max	Unit
T _{amb} = -	40 °C to +125 °C		•			
V_{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = 100 μA; V _{CC} = 1.65 V to 5.5 V	-	-	0.1	V
		I _O = 4 mA; V _{CC} = 1.65 V	-	-	0.7	V
		I_{O} = 8 mA; V_{CC} = 2.3 V	-	-	0.45	V
		I _O = 12 mA; V _{CC} = 2.7 V	-	-	0.6	V
		I_{O} = 24 mA; V_{CC} = 3.0 V	-	-	0.8	V
		I_{O} = 32 mA; V_{CC} = 4.5 V	-	-	8.0	V
V _{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I_{O} = -100 μ A; V_{CC} = 1.65 V to 5.5 V	V _{CC} - 0.1	-	-	V
		I _O = -4 mA; V _{CC} = 1.65 V	0.95	-	-	V
		I _O = -8 mA; V _{CC} = 2.3 V	1.7	-	-	V
		I _O = -12 mA; V _{CC} = 2.7 V	1.9	-	-	V
		I_{O} = -24 mA; V_{CC} = 3.0 V	2.0	-	-	V
		I_{O} = -32 mA; V_{CC} = 4.5 V	3.4	-	-	V
I _I	input leakage current	V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V	-	-	±1	μA
I _{OFF}	power-off leakage current	V _I or V _O = 5.5 V; V _{CC} = 0 V	-	-	±2	μΑ
I _{CC}	supply current	$V_I = 5.5 \text{ V or GND}; V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}; I_O = 0 \text{ A}$	-	-	4	μΑ
Δl _{CC}	additional supply current	V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 2.3 V to 5.5 V	-	-	500	μA

^[1] Typical values are measured at maximum V_{CC} and T_{amb} = 25 °C.

11. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 13.

Symbol	Parameter	Conditions	-40	-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ [1]	Max	Min	Max	
t _{pd}	propagation delay	A, B, C to Y; see <u>Fig. 12</u> [2]						
		V _{CC} = 1.65 V to 1.95 V	1.0	6.0	14.4	1.0	18.0	ns
		V _{CC} = 2.3 V to 2.7 V	0.5	3.5	8.3	0.5	10.4	ns
		V _{CC} = 2.7 V	0.5	4.2	8.5	0.5	10.6	ns
		V _{CC} = 3.0 V to 3.6 V	0.5	3.8	6.3	0.5	7.9	ns
		V _{CC} = 4.5 V to 5.5 V	0.5	3.0	5.1	0.5	6.4	ns
C _{PD}	power dissipation capacitance	$V_{CC} = 3.3 \text{ V}; V_I = \text{GND to } V_{CC}$ [3]	-	20	-	-	-	pF

^[1] Typical values are measured at nominal V_{CC} and at T_{amb} = 25 °C.

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

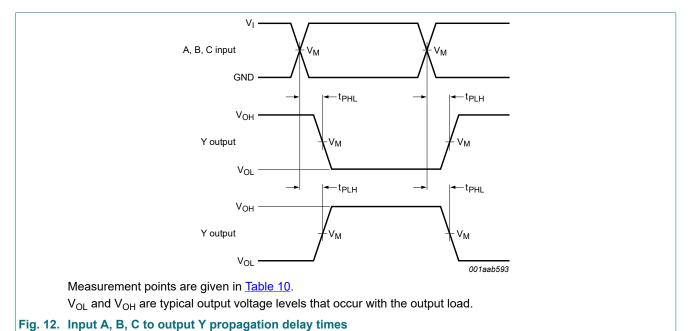
 V_{CC} = supply voltage in V;

N = number of inputs switching; $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of outputs.

t_{pd} is the same as t_{PLH} and t_{PHL}.
 C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

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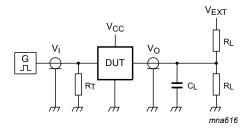
11.1. Waveforms and test circuit



rig. 12. Input A, B, C to output 1 propagation delay time

Table 10. Measurement points

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Supply voltage	Input	Output			
V _{CC}	V _M	V _M			
1.65 V to 1.95 V	0.5 × V _{CC}	0.5 × V _{CC}			
2.3 V to 2.7 V	0.5 × V _{CC}	0.5 × V _{CC}			
2.7 V	1.5 V	1.5 V			
3.0 V to 3.6 V	1.5 V	1.5 V			
4.5 V to 5.5 V	0.5 × V _{CC}	0.5 × V _{CC}			



Test data is given in Table 11.

Definitions for test circuit:

R_I = Load resistance;

C_L = Load capacitance including jig and probe capacitance;

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator;

V_{EXT} = External voltage for measuring switching times.

Fig. 13. Test circuit for measuring switching times

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Table 11. Test data

Supply voltage	Input		Load	Load	
V _{CC}	VI	$t_r = t_f$	CL	R _L	t _{PLH} , t _{PHL}
1.65 V to 1.95 V	V _{CC}	≤ 2.0 ns	30 pF	1 kΩ	open
2.3 V to 2.7 V	V _{CC}	≤ 2.0 ns	30 pF	500 Ω	open
2.7 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open
4.5 V to 5.5 V	V _{CC}	≤ 2.5 ns	50 pF	500 Ω	open

12. Transfer characteristics

Table 12. Transfer characteristics

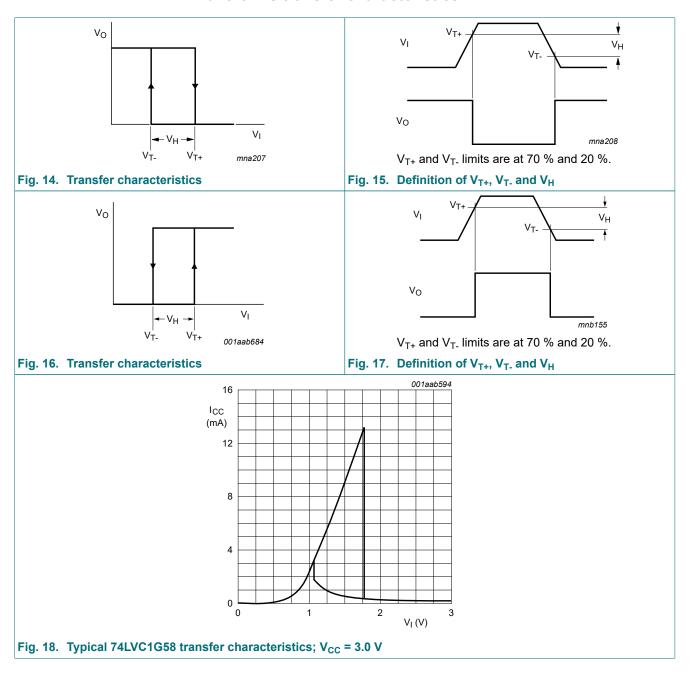
At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ [1]	Max	Min	Max	
V _{T+}	positive-going threshold voltage	see Fig. 14, Fig. 15, Fig. 16 and Fig. 17						
		V _{CC} = 1.8 V	0.70	1.02	1.20	0.67	1.20	V
		V _{CC} = 2.3 V	1.11	1.42	1.60	1.08	1.60	V
		V _{CC} = 3.0 V	1.50	1.79	2.00	1.47	2.00	V
		V _{CC} = 4.5 V	2.16	2.52	2.74	2.13	2.74	V
		V _{CC} = 5.5 V	2.61	2.99	3.33	2.58	3.33	V
V _T -	negative-going threshold voltage	see <u>Fig. 14</u> , <u>Fig. 15</u> , <u>Fig. 16</u> and <u>Fig. 17</u>						
		V _{CC} = 1.8 V	0.30	0.53	0.72	0.30	0.75	V
		V _{CC} = 2.3 V	0.58	0.77	1.00	0.58	1.03	V
		V _{CC} = 3.0 V	0.80	1.04	1.30	0.80	1.33	V
		V _{CC} = 4.5 V	1.21	1.55	1.90	1.21	1.93	V
		V _{CC} = 5.5 V	1.45	1.86	2.29	1.45	2.32	V
V _H	hysteresis voltage	(V _{T+} - V _{T-}); see <u>Fig. 14</u> , <u>Fig. 15</u> , <u>Fig. 16</u> and <u>Fig. 17</u>						
		V _{CC} = 1.8 V	0.30	0.48	0.62	0.23	0.62	V
		V _{CC} = 2.3 V	0.40	0.64	0.80	0.34	0.80	V
		V _{CC} = 3.0 V	0.50	0.75	1.00	0.44	1.00	V
		V _{CC} = 4.5 V	0.71	0.97	1.20	0.65	1.20	V
		V _{CC} = 5.5 V	0.71	1.13	1.40	0.65	1.40	V

^[1] Typical values are measured at T_{amb} = 25 °C.

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12.1. Waveforms transfer characteristics



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13. Package outline

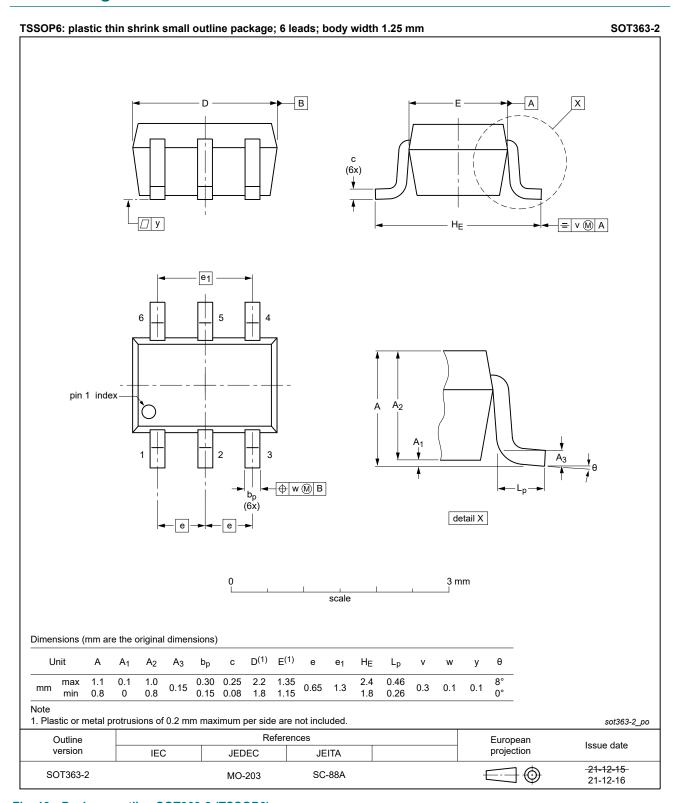


Fig. 19. Package outline SOT363-2 (TSSOP6)

Product data sheet

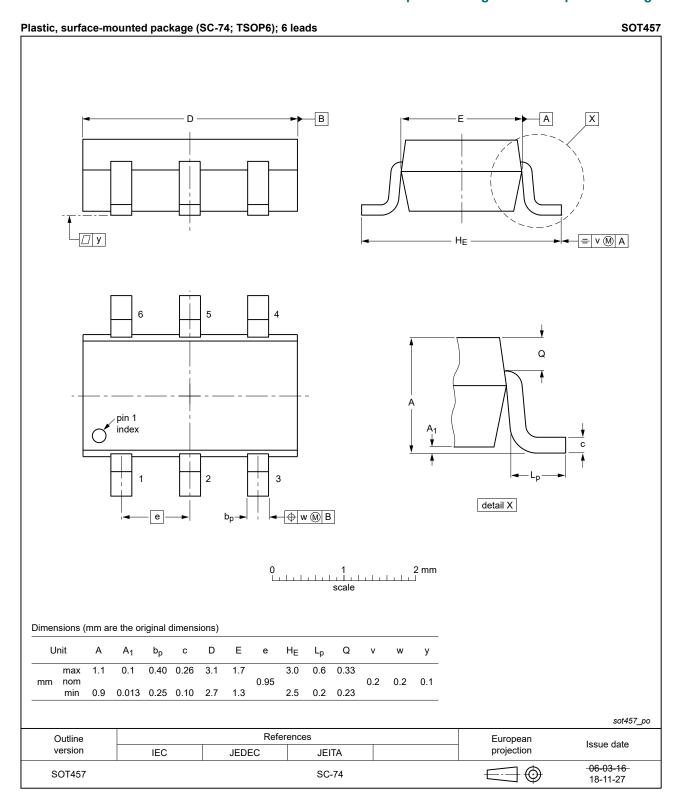


Fig. 20. Package outline SOT457 (SC-74; TSOP6)

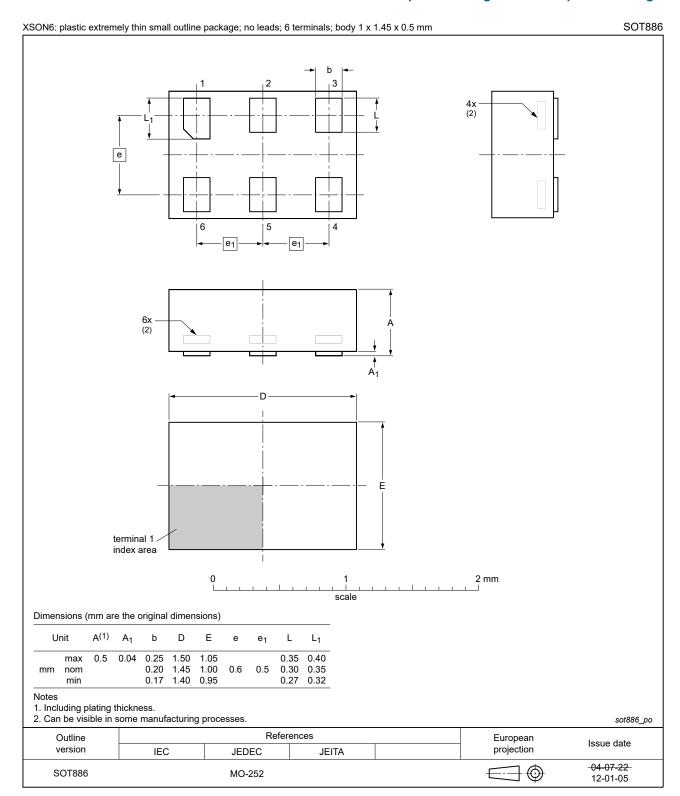


Fig. 21. Package outline SOT886 (XSON6)

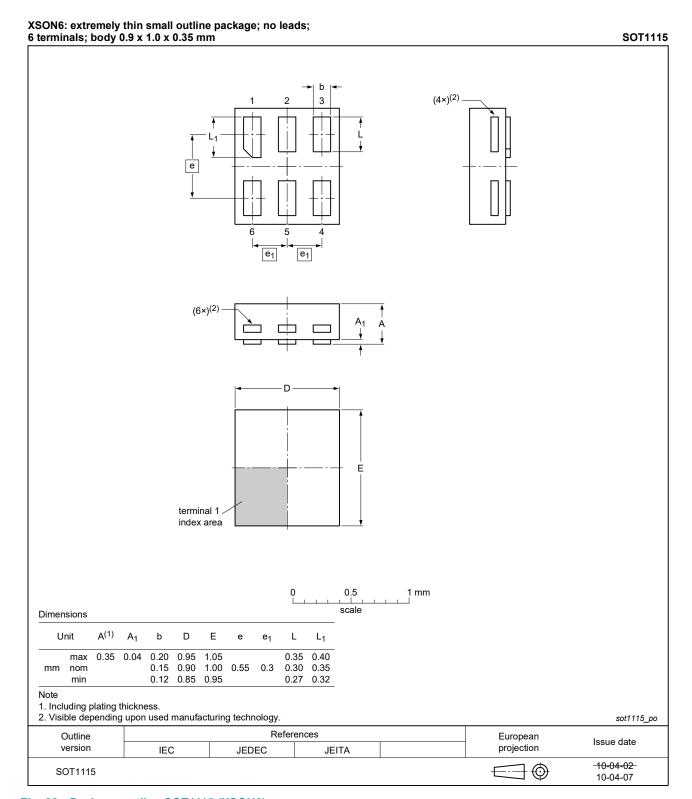


Fig. 22. Package outline SOT1115 (XSON6)

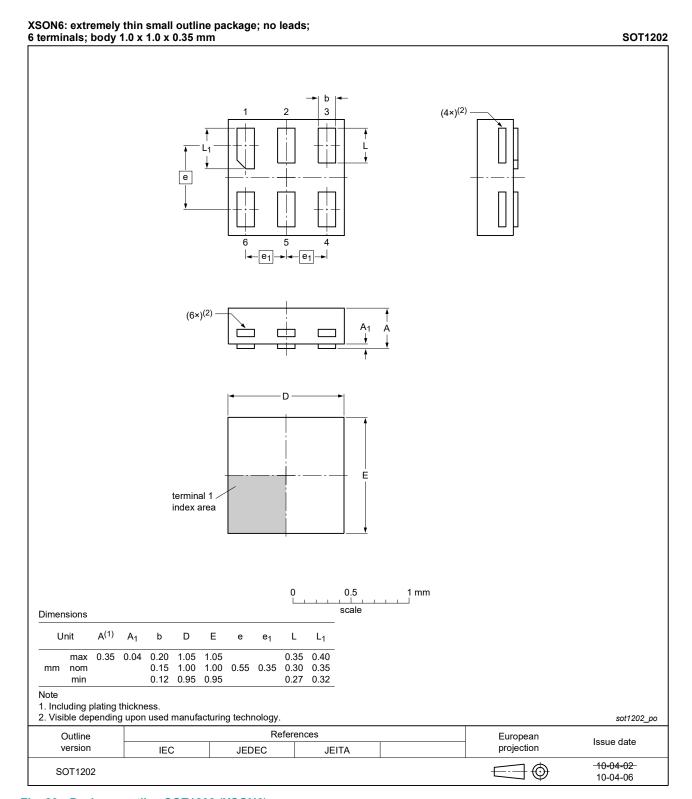


Fig. 23. Package outline SOT1202 (XSON6)

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14. Abbreviations

Table 13. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
TTL	Transistor-Transistor Logic

15. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74LVC1G58 v.12	20230818	Product data sheet	-	74LVC1G58 v.11		
Modifications:	Section 2: I	<u>Section 2</u> : ESD specification updated according to the latest JEDEC standard.				
74LVC1G58 v.11	20220201	Product data sheet	-	74LVC1G58 v.10		
Modifications:	Package So	OT363 (SC-88) changed t	to SOT363-2 (TSSOP6).			
74LVC1G58 v.10	20210607	Product data sheet	-	74LVC1G58 v.9		
Modifications:	guidelines of Legal texts Type numb Section 1 a Section 8: I	 Section 1 and Section 2 updated. Section 8: Derating values for P_{tot} total power dissipation updated. 				
74LVC1G58 v.9	20161207	Product data sheet	-	74LVC1G58 v.8		
Modifications:	• <u>Table 8</u> : Th	<u>Table 8</u> : The maximum limits for leakage current and supply current have changed.				
74LVC1G58 v.8	20140422	Product data sheet	-	74LVC1G58 v.7		
Modifications:	• Package ou	Package outline drawing of SOT886 (Fig. 21) modified.				
74LVC1G58 v.7	20111206	Product data sheet	-	74LVC1G58 v.6		
Modifications:	Legal page	Legal pages updated.				
74LVC1G58 v.6	20110923	Product data sheet	-	74LVC1G58 v.5		
74LVC1G58 v.5	20101015	Product data sheet	-	74LVC1G58 v.4		
74LVC1G58 v.4	20090427	Product data sheet	-	74LVC1G58 v.3		
74LVC1G58 v.3	20070827	Product data sheet	-	74LVC1G58 v.2		
74LVC1G58 v.2	20070222	Product data sheet	-	74LVC1G58 v.1		
74LVC1G58 v.1	20040915	Product data sheet	-	-		

16. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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Low-power configurable multiple function gate

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